MPSW55, MPSW56

One Watt Amplifier Transistors

PNP Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage	MPSW55 MPSW56	V _{CEO}	-60 -80	Vdc
Collector – Base Voltage MPSW55 MPSW56		V _{CBO}	-60 -80	Vdc
Emitter – Base Voltage		V _{EBO}	-4.0	Vdc
Collector Current – Continuous		Ι _C	-500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C		P _D	1.0 8.0	W mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C		PD	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	n	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

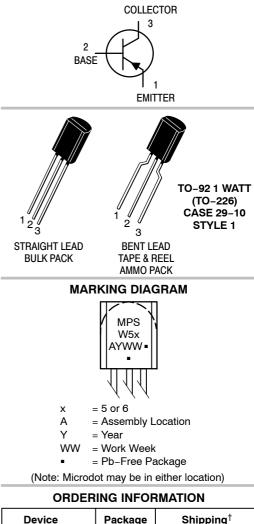
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com



Device	Package	Shipping [†]
MPSW55G	TO–92 (Pb–Free)	5000 Units/Bulk
MPSW55RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel
MPSW56RLRP	TO-92	2000/Ammo Pack
MPSW56RLRPG	TO-92 (Pb-Free)	2000/Ammo Pack

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

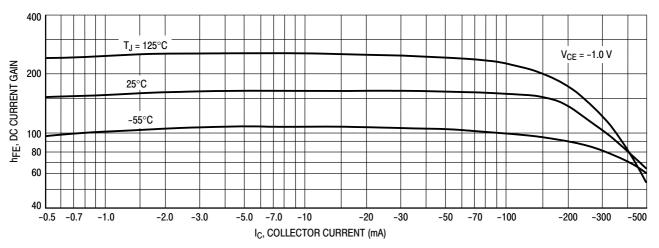
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPSW55, MPSW56

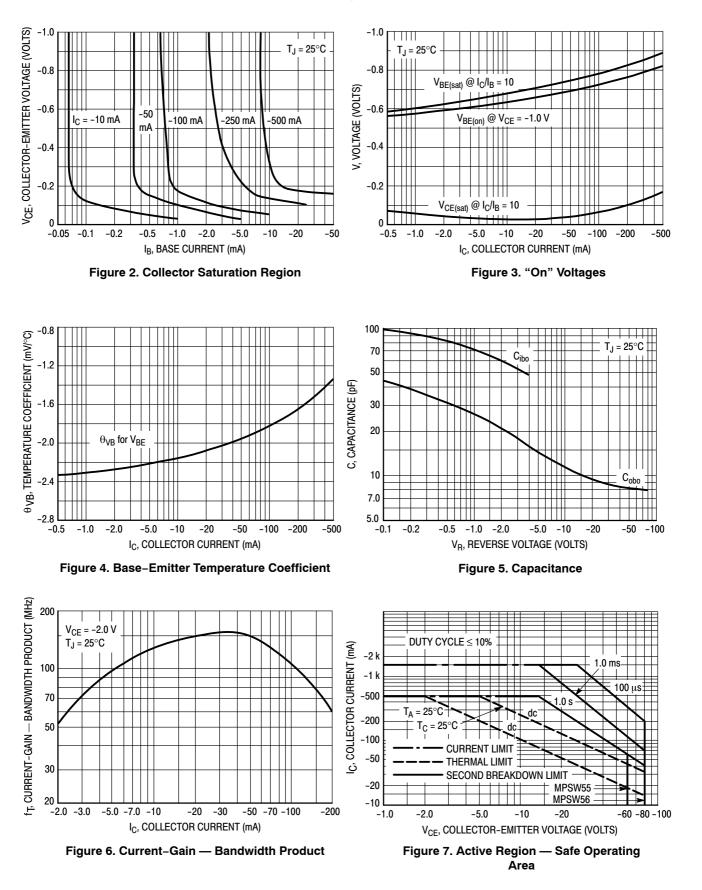
ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS	·			•	
Collector – Emitter Breakdown Voltage (Note 1) ($I_C = -1.0 \text{ mAdc}, I_B = 0$)	MPSW55 MPSW56	V _{(BR)CEO}	-60 -80		Vdc
Emitter – Base Breakdown Voltage ($I_E = -100 \ \mu Adc, I_C = 0$)		V _{(BR)EBO}	-4.0	_	Vdc
	MPSW55 MPSW56	I _{CES}		-0.5 -0.5	μAdc
Collector Cutoff Current $(V_{CB} = -40 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -60 \text{ Vdc}, I_E = 0)$	MPSW55 MPSW56	I _{CBO}		-0.1 -0.1	μAdc
Emitter Cutoff Current ($V_{EB} = -3.0$ Vdc, $I_C = 0$)		I _{EBO}	-	-0.1	μAdc
ON CHARACTERISTICS ⁽¹⁾	·			•	
DC Current Gain (I _C = -50 mAdc, V _{CE} = -1.0 Vdc) (I _C = -250 mAdc, V _{CE} = -1.0 Vdc)		h _{FE}	100 50		-
Collector – Emitter Saturation Voltage ($I_C = -250$ mAdc, $I_B = -10$ mAdc)		V _{CE(sat)}	_	-0.5	Vdc
Base-Emitter On Voltage ($I_C = -250 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc}$)		V _{BE(on)}	_	-1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product (I _C = -250 mAdc, V _{CE} = -5.0 Vdc, f = 20 MHz)		f _T	50	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, f = 1.0 MHz)		C _{obo}	_	15	pF

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

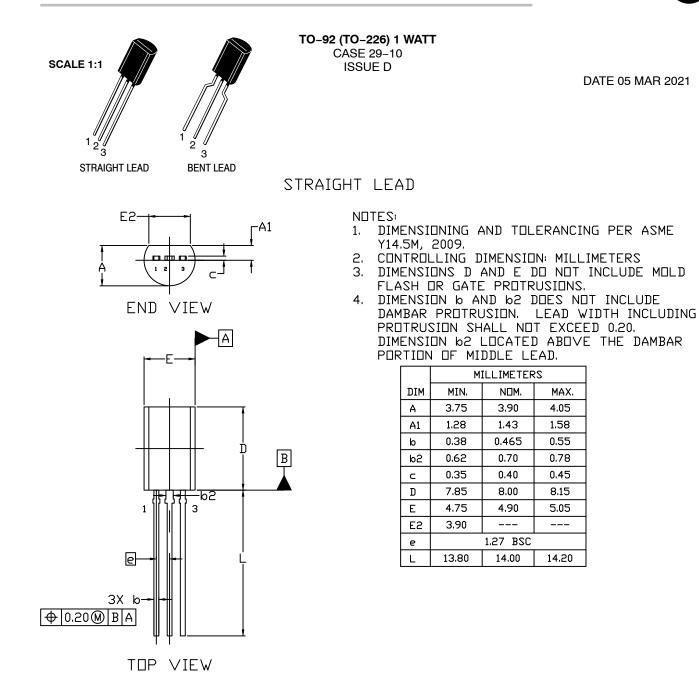






MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





STYLES AND MARKING ON PAGE 3

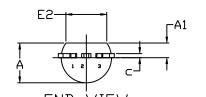
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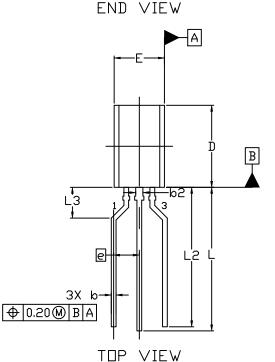


TO-92 (TO-226) 1 WATT CASE 29–10 ISSUE D

DATE 05 MAR 2021

FORMED LEAD





NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS,
- 4. DIMENSION ७ AND ७2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION ७2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
Α	3.75	3.90	4.05	
A1	1.28	1.43	1.58	
σ	0.38	0.465	0.55	
b2	0.62	0.70	0.78	
с	0.35	0.40	0.45	
D	7.85	8.00	8.15	
Е	4.75	4.90	5.05	
E2	3.90			
e	2.50 BSC			
L	13.80	14.00	14.20	
L2	13.20	13.60	14.00	
L3	3.00 REF			

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DATE 05 MAR 2021

	EMITTER BASE COLLECTOR
	GATE SOURCE & SUBSTRATE DRAIN
2.	ANODE CATHODE & ANODE CATHODE
2.	ANODE GATE CATHODE
2.	COLLECTOR EMITTER BASE

STYLE 2: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 7: PIN 1. SOURCE 2. DRAIN 3. GATE STYLE 12: PIN 1. MAIN TERMINAL 1 2. GATE 3. MAIN TERMINAL 2 STYLE 17: PIN 1. COLLECTOR 2. BASE 3. EMITTER STYLE 22: PIN 1. SOURCE 2. GATE 3. DRAIN STYLE 27: PIN 1. MT 2. SUBSTRATE 3. MT STYLE 32 PIN 1. BASE 2. COLLECTOR 3. EMITTER

style Pin	1. 2.	ANODE ANODE CATHODE
Style Pin	1. 2.	DRAIN GATE SOURCE & SUBSTRATE
style Pin	1. 2.	ANODE 1 GATE CATHODE 2
style Pin	1. 2.	ANODE CATHODE NOT CONNECTED
style Pin	1. 2.	GATE SOURCE DRAIN
style Pin	1. 2.	CATHODE ANODE GATE
style Pin	1. 2.	RETURN INPUT OUTPUT

STYLE 4: PIN 1. CATHODE STYLE 5: 2. CATHODE 3. ANODE STYLE 9: PIN 1. BASE 1 2. EMITTER 3. BASE 2 STYLE 14: PIN 1. EMITTER 2. COLLECTOR 3. BASE STYLE 19: PIN 1. GATE 2. ANODE 3. CATHODE STYLE 24: PIN 1. EMITTER 2. COLLECTOR/ANODE 3. CATHODE STYLE 29: PIN 1. NOT CONNECTED 2. ANODE 3. CATHODE STYLE 34: PIN 1. INPUT

2. GROUND 3. LOGIC

PIN 1. DRAIN 2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

GENERIC MARKING DIAGRAM*

XXXXX XXXXX ALYW

XXXX = Specific Device Code

- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
 - = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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